

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	50	(((((LDD with gate with (overlying or overlapping)) and pixel) and TFT) and (driver adj circuit)) and (second adj gate adj electrode)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/07/04 13:20
S2	39	S1 and (gate with second with layer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/07/04 13:39
S3	2	S2 and (column with spacer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/07/04 13:36
S4	2	S1 and (column with spacer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/02 17:20
S5	66	column with spacer with pixel	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/07/04 13:38
S6	22	S5 and (n-channel or p-channel)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/07/04 13:39
S7	16	S6 and (gate with second with layer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/07/04 13:42
S8	27	S5 and (gate with second with layer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/07/04 13:42
S9	5	"6639265"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/18 11:53

## EAST Search History

S10	63	(((((LDD with gate with (overlying or overlapping))) and pixel) and TFT) and (driver adj circuit)) and (second adj gate adj electrode)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/02 17:20
S11	2	S10 and (column with spacer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/02 17:22
S12	25	(column with shape with spacer with pixel)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/02 17:32
S13	22	S12 and capacitor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/02 17:33
S14	20	S13 and (n adj channel) and (p adj channel)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/02 17:34
S15	5	"6639265"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/06 12:00
S16	1222	(n adj channel) and (p adj channel) and (driver adj circuit)and LDD	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/06 12:03
S17	1	S16 and (LDD with graded)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 09:08
S18	357	(pixel adj (TFT or (thin adj film adj transistor))) with LDD	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/06 13:07
S19	231	S18 and (storage adj capacitor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/06 13:07

## EAST Search History

S20	276	(LDD with graded)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 09:09
S21	163	S20 and (n adj channel)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 09:31
S22	0	S21 and (decreasing with toward with channel)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 09:10
S23	8	S21 and (decreasing with channel)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 09:10
S24	821	257/303.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 09:40
S25	23	(thin adj film) and CMOS and (graded with LDD)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 09:43
S26	2	S25 and driver	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 09:42
S27	1127	(thin adj film) and CMOS and (LDD) and (driver adj circuit)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 09:44
S28	2197	LDD and pixel and capacitor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/18 11:54
S29	8	LDD and pixel and (storage with capacitor) and (gate with insulator with thickness with capacitor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/18 11:59

## EAST Search History

S30	28	LDD and pixel and (storage with capacitor) and (gate with (insulator or dielectric) with thickness with capacitor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/18 11:59
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